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Dual 4-bit synchronous binary counter

Rev. 4 — 10 May 2016

**Product data sheet** 

### 1. General description

The 74HC4520; 74HCT4520 are dual 4-bit internally synchronous binary counters with two clock inputs (nCP0 and nCP1). They have buffered outputs from all 4 bit positions (nQ0 to nQ3) and an asynchronous master reset input (nMR). The counter advances on the LOW-to-HIGH transition of nCP0 when nCP1 is HIGH. It also advances on the HIGH-to-LOW transition of nCP1 when nCP0 is LOW. Either nCP0 or nCP1 may be used as the clock input to the counter. The other clock input may be used as a clock enable input. A HIGH on nMR, resets the counter (nQ0 to nQ3 = LOW) independent of nCP0 and nCP1. Inputs include clamp diodes. It enables the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

### 2. Features and benefits

- Complies with JEDEC standard no. 7A
- Input levels:
  - ◆ For 74HC4520: CMOS level
  - For 74HCT4520: TTL level
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C

### 3. Applications

- Multistage synchronous counting
- Multistage asynchronous counting
- Frequency dividers



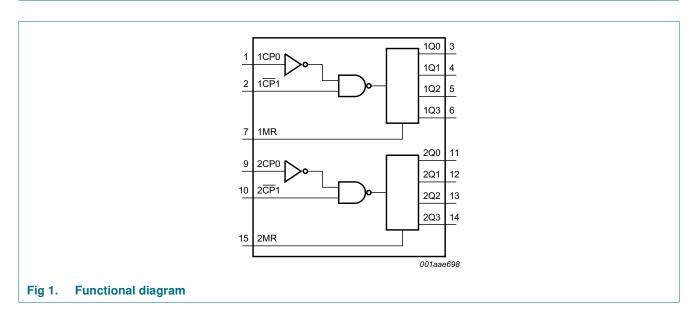
Dual 4-bit synchronous binary counter

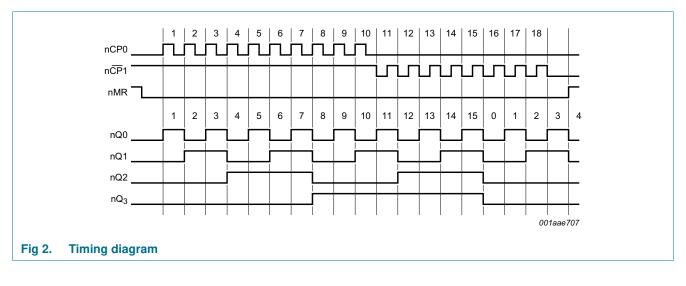
## 4. Ordering information

#### Table 1.Ordering information

Type number	Package	Package										
	Temperature range	Name	Description	Version								
74HC4520D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1								
74HCT4520D			body width 3.9 mm									
74HC4520DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1								
74HCT4520DB			body width 5.3 mm									
74HC4520PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1								

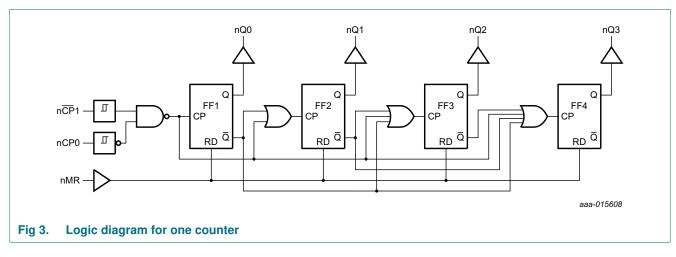
## 5. Functional diagram



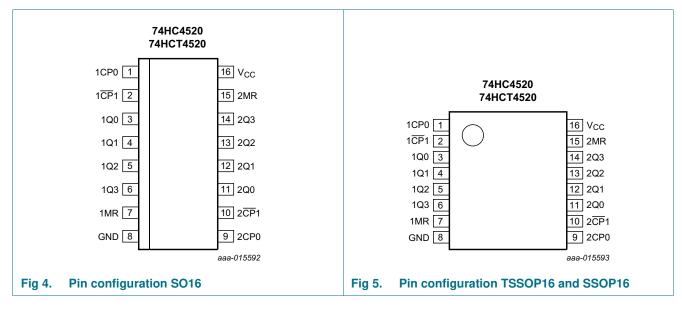


# 74HC4520; 74HCT4520

Dual 4-bit synchronous binary counter



## 6. Pinning information



### 6.1 Pinning

### 6.2 Pin description

Table 2.	Pin	description
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Symbol	Pin	Description
1CP0, 2CP0	1, 9	clock input (LOW-to-HIGH edge-triggered)
1 <u>CP</u> 1, 2 <u>CP</u> 1	2, 10	clock input (HIGH-to-LOW edge-triggered)
1Q0 to 1Q3	3, 4, 5, 6	output
1MR, 2MR	7, 15	asynchronous master reset input (active HIGH)
GND	8	ground (0 V)
2Q0 to 2Q3	11, 12, 13, 14	output
V <sub>CC</sub>	16	supply voltage

74HC\_HCT4520

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# 7. Functional description

Table 3.   Function table <sup>[1]</sup>	l		
nCP0	nCP1	nMR	Mode
$\uparrow$	Н	L	counter advances
L	$\downarrow$	L	counter advances
$\downarrow$	X	L	no change
Х	↑	L	no change
$\uparrow$	L	L	no change
Н	$\downarrow$	L	no change
Х	Х	Н	nQ0 to nQ3 = LOW

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care;  $\uparrow = positive-going transition; \downarrow = negative-going transition.$ 

### 8. Limiting values

#### Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5$ V or $V_{I} > V_{CC} + 0.5$ V		-	±20	mA
I <sub>ОК</sub>	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V		-	±20	mA
lo	output current	$V_{O} = -0.5$ V to $V_{CC}$ + 0.5 V		-	±25	mA
I <sub>CC</sub>	supply current			-	50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	SO16 and (T)SSOP16 package	[1]	-	500	mW

[1] For SO16 package: above 70  $^{\circ}\text{C}$  the value of P<sub>tot</sub> derates linearly at 8 mW/K.

For (T)SSOP16 packages: above 60  $^\circ$ C the value of P<sub>tot</sub> derates linearly at 5.5 mW/K.

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## 9. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	7	74HC4520			74HCT4520		
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

# **10. Static characteristics**

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 ℃	Unit	
			Min	Тур	Max	Min	Max	Min	Max	-	
74HC45	20		•	1			1	1		1	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V	
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V	
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V	
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V	
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V	
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V	
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$									
	output voltage	$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V	
		$I_{O} = -20 \ \mu A; V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V	
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V	
		$I_{O} = -4.0; V_{CC} = 4.5 V$	3.98	4.32	-	3.84	-	3.7	-	V	
		$I_{O} = -5.2; V_{CC} = 6.0 V$	5.48	5.81	-	5.34	-	5.2	-	V	
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>									
	output voltage	$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V	
		$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V	
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V	
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V	
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V	
lı	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1.0	-	±1.0	μA	
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 6.0 \ V \end{array}$	-	-	8.0	-	80.0	-	160.0	μA	

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#### Table 6. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to +125 °C		Unit		
			Min	Тур	Max	Min	Max	Min	Max			
CI	input capacitance		-	3.5	-	-	-	-	-	pF		
74HCT4	520		1	1		1		1	<u> </u>			
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V		
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V		
V <sub>OH</sub>	HIGH-level											
	output voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V		
		I <sub>O</sub> = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V		
V <sub>OL</sub>	LOW-level $V_I = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$											
	output voltage	l <sub>O</sub> = 20 μA	-	0	0.1	-	0.1	-	0.1	V		
		l <sub>O</sub> = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V		
lı	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1.0	-	±1.0	μA		
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	8.0	-	80.0	-	160.0	μA		
$\Delta I_{CC}$	additional	per input pin; $V_I = V_{CC} - 2.1 V$ ;	other ir	puts at	V <sub>CC</sub> or	GND; V <sub>C</sub>	<sub>C</sub> = 4.5 V	to 5.5 V; I	<sub>O</sub> = 0 A			
	supply current	pin nCP0, nCP1	-	80	288	-	360	-	392	μA		
		pin nMR	-	150	540	-	675	-	735	μA		
CI	input capacitance		-	3.5	-	-	-	-	-	pF		

### **11. Dynamic characteristics**

#### Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit, see <u>Figure 7</u>.

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	–40 °C to	+125 °C	Unit	
			Min	Тур	Max	Min	Max	Min	Max		
74HC452	20										
t <sub>pd</sub>	propagation	nCP0 to nQn; see Figure 6 [1]									
	delay	V <sub>CC</sub> = 2.0 V	-	77	240	-	300	-	360	ns	
		$V_{CC} = 4.5 V$	-	28	48	-	60	-	72	ns	
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	24	-	-	-	-	-	ns	
		V <sub>CC</sub> = 6.0 V	-	22	41	-	51	-	61	ns	
		nCP1 to nQn; see Figure 6									
		V <sub>CC</sub> = 2.0 V	-	77	240	-	300	-	360	ns	
		$V_{CC} = 4.5 V$	-	28	48	-	60	-	72	ns	
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	24	-	-	-	-	-	ns	
		$V_{CC} = 6.0 V$	-	22	41	-	51	-	61	ns	

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Symbol	Parameter	Conditions		25 °C		–40 °C to	+85 °C	–40 °C to	+125 °C	Unit		
			Min	Тур	Max	Min	Max	Min	Max			
t <sub>PHL</sub>	HIGH to LOW	nMR to nQn; see Figure 6						1				
	propagation	V <sub>CC</sub> = 2.0 V	-	44	150	-	190	-	225	ns		
	delay	V <sub>CC</sub> = 4.5 V	-	16	30	-	38	-	45	ns		
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	13	-	-	-	-	-	ns		
		V <sub>CC</sub> = 6.0 V	-	13	26	-	33	-	38	ns		
t <sub>t</sub>	transition	nQn; see Figure 6 [2]										
	time	V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns		
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns		
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns		
tw	pulse width	nCP0, nCP1 HIGH or LOW; see Figure 6										
		V <sub>CC</sub> = 2.0 V	80	22	-	100	-	120	-	ns		
		V <sub>CC</sub> = 4.5 V	16	8	-	20	-	24	-	ns		
		V <sub>CC</sub> = 6.0 V	14	6	-	17	-	20	-	ns		
		nMR HIGH; see <u>Figure 6</u>						1				
		V <sub>CC</sub> = 2.0 V	120	39	-	150	-	180	-	ns		
		V <sub>CC</sub> = 4.5 V	24	14	-	30	-	36	-	ns		
		V <sub>CC</sub> = 6.0 V	20	11	-	26	-	31	-	ns		
t <sub>rec</sub>	recovery time	nMR to nCP0, nCP1; see Figure 6										
		V <sub>CC</sub> = 2.0 V	0	-28	-	0	-	0	-	ns		
		V <sub>CC</sub> = 4.5 V	0	-10	-	0	-	0	-	ns		
		V <sub>CC</sub> = 6.0 V	0	-8	-	0	-	0	-	ns		
t <sub>su</sub>	set-up time	nCP0 to nCP1; nCP1 to nCP0; see	Figur	e 6	11		1	1	1			
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns		
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns		
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns		
f <sub>max</sub>	maximum	nCP0, nCP1; see Figure 6						1				
	frequency	V <sub>CC</sub> = 2.0 V	6	19	-	4.8	-	4	-	MHz		
		V <sub>CC</sub> = 4.5 V	30	58	-	24	-	20	-	MHz		
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	68	-	-	-	-	-	MHz		
		V <sub>CC</sub> = 6.0 V	35	69	-	28	-	24	-	MHz		
C <sub>PD</sub>	power dissipation capacitance	$V_I = GND$ to $V_{CC}$ ; $V_{CC} = 5 V$ ; [3] $f_i = 1 MHz$	-	29	-	-	-	-	-	pF		

#### Dynamic characteristics ... continued Table 7.

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Dual 4-bit synchronous binary counter

Symbol	Parameter	Conditions		25 °C		–40 °C to	+85 °C	–40 °C to	• +125 °C	Unit		
			Min	Тур	Max	Min	Max	Min	Max			
74HCT4	520	1										
t <sub>pd</sub>	propagation	nCP0 to nQn; see Figure 6										
	delay	V <sub>CC</sub> = 4.5 V	-	28	53	-	66	-	80	ns		
		$V_{CC} = 5.0 \text{ V}; C_{L} = 15 \text{ pF}$	-	24	-	-	-	-	-	ns		
		nCP1 to nQn; see Figure 6 [1]										
		V <sub>CC</sub> = 4.5 V	-	25	53	-	66	-	80	ns		
		$V_{CC} = 5.0 \text{ V}; C_{L} = 15 \text{ pF}$	-	24	-	-	-	-	-	ns		
t <sub>PHL</sub>	HIGH to LOW	nMR to nQn; see Figure 6										
	propagation	V <sub>CC</sub> = 4.5 V	-	16	35	-	44	-	53	ns		
	delay	$V_{CC} = 5.0 \text{ V}; C_{L} = 15 \text{ pF}$	-	13	-	-	-	-	-	ns		
t <sub>t</sub>	transition	nQn; see Figure 6 [2]										
	time	V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns		
t <sub>W</sub>	pulse width	nCP0, nCP1 HIGH or LOW; see Figure 6										
		V <sub>CC</sub> = 4.5 V	20	10	-	25	-	30	-	ns		
		nMR HIGH; see Figure 6										
		V <sub>CC</sub> = 4.5 V	20	12	-	25	-	30	-	ns		
t <sub>rec</sub>	recovery time	nMR to nCP0, nCP1; see Figure 6										
		V <sub>CC</sub> = 4.5 V	0	-8	-	0	-	0	-	ns		
t <sub>su</sub>	set-up time	nCP0 to nCP1; nCP1 to nCP0; see	Figur	e 6								
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns		
f <sub>max</sub>	maximum	nCP0, nCP1; see Figure 6										
	frequency	V <sub>CC</sub> = 4.5 V	30	58	-	24	-	20	-	MHz		
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	64	-	-	-	-	-	MHz		
C <sub>PD</sub>	power dissipation capacitance	$V_{I} = \text{GND to } V_{CC} - 1.5 \text{ V}; \qquad [3]$ $V_{CC} = 5 \text{ V}; f_{i} = 1 \text{ MHz}$	-	24	-	-	-	-	-	pF		

# Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V);  $C_L$  = 50 pF unless otherwise specified; for test circuit, see Figure 7

[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W):

 $P_{D} = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o$  = output frequency in MHz;

 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

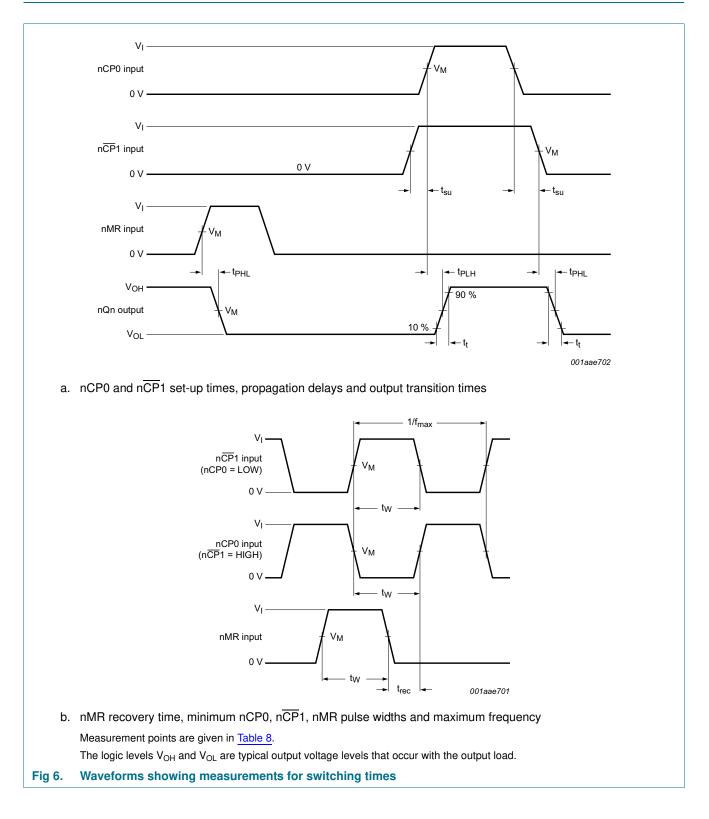
N = number of inputs switching;

 $\sum (C_L \times V_{CC}{}^2 \times f_o)$  = sum of outputs.

# 74HC4520; 74HCT4520

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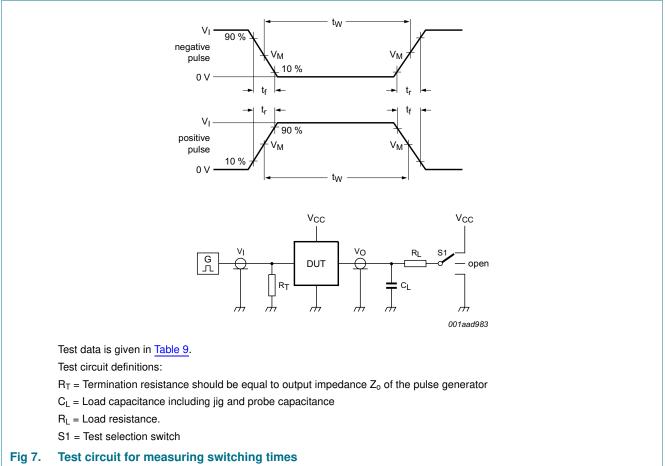
### 12. Waveforms



# 74HC4520; 74HCT4520

#### Dual 4-bit synchronous binary counter

Table 8. Measurement points									
Туре	Input	Output							
	V <sub>M</sub>	VI	V <sub>M</sub>						
74HC4520	$0.5  imes V_{CC}$	GND to V <sub>CC</sub>	$0.5  imes V_{CC}$						
74HCT4520	1.3 V	GND to 3 V	1.3 V						

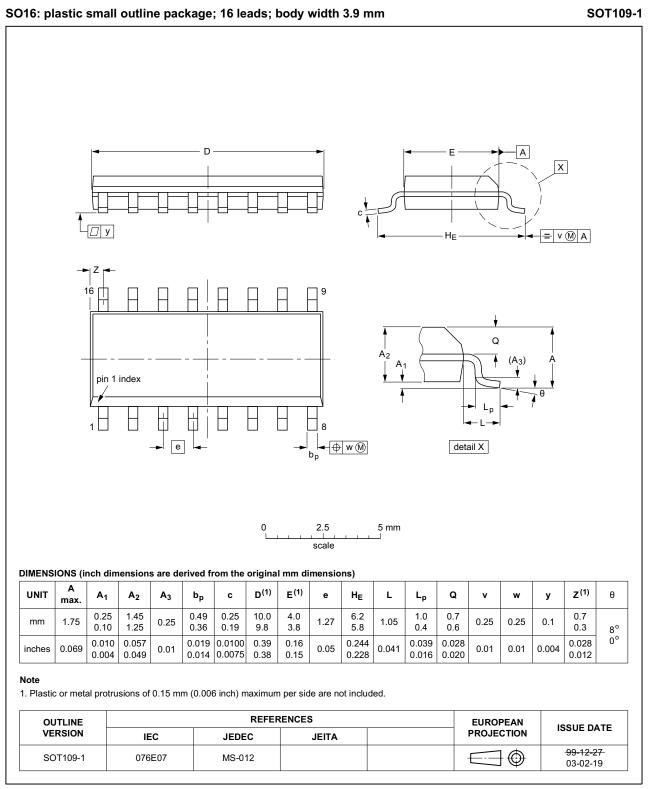


#### Table 9. Test data

Туре	Input		Load		S1 position
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>
74HC4520	GND to V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT4520	GND to 3 V	6 ns	15 pF, 50 pF	1 kΩ	open

**Dual 4-bit synchronous binary counter** 

### 13. Package outline



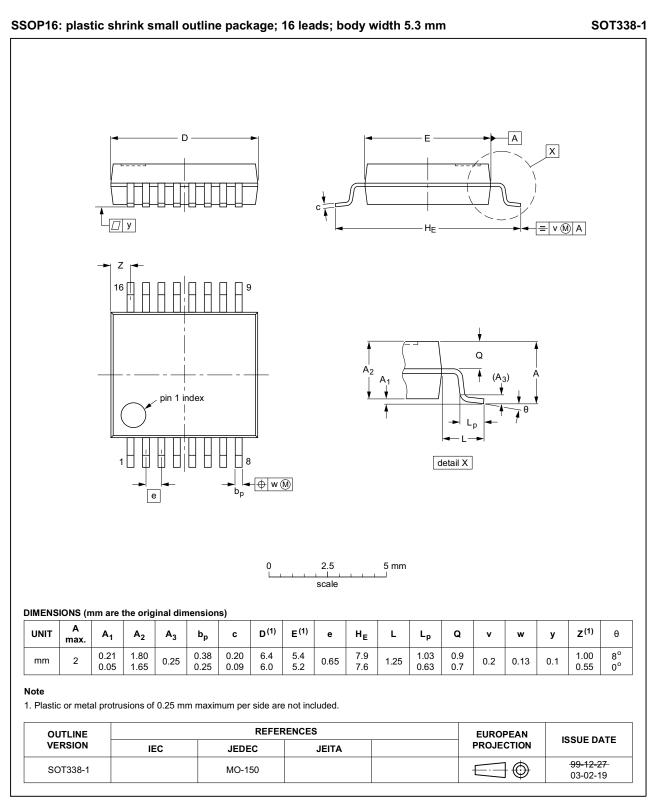
#### Fig 8. Package outline SOT109-1 (SO16)

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74HC\_HCT4520

All info

Dual 4-bit synchronous binary counter



#### Fig 9. Package outline SOT338-1 (SSOP16)

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Dual 4-bit synchronous binary counter

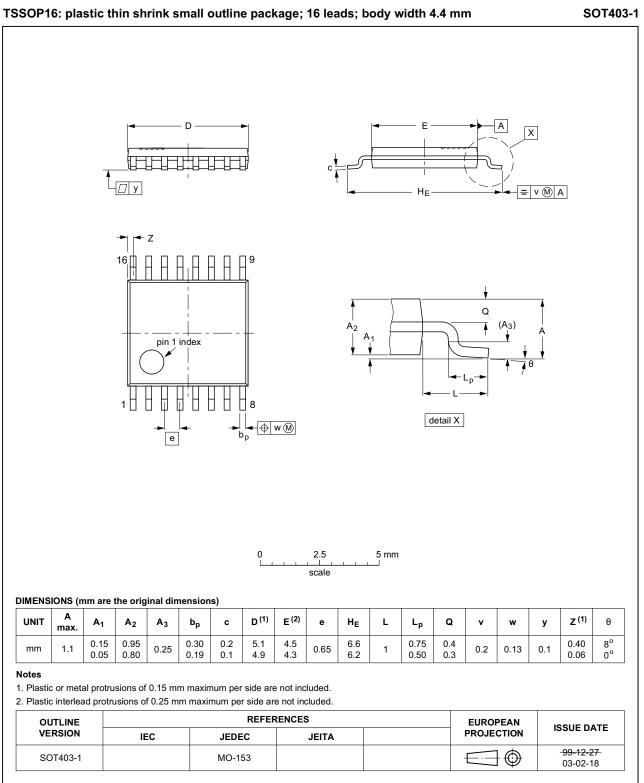


Fig 10. Package outline SOT403-1 (TSSOP16)

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Dual 4-bit synchronous binary counter

# 14. Abbreviations

Table 10. Abbreviations		
Acronym	Description	
CMOS	Complementary Metal-Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
LSTTL	Low-power Schottky Transistor-Transistor Logic	
MM	Machine Model	
TTL	Transistor-Transistor Logic	

# **15. Revision history**

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4520 v.4	20160510	Product data sheet	-	74HC_HCT4520 v.3
Modifications:	Type numbers	s 74HC4520N and 74HCT4520	ON (SOT38-4) remov	/ed.
74HC_HCT4520 v.3	20141204	Product data sheet	-	74HC_HCT4520_CNV v.2
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>			
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>			
74HC_HCT4520_CNV v.2	19930927	Product specification	-	-

**Dual 4-bit synchronous binary counter** 

### 16. Legal information

#### 16.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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# 74HC4520; 74HCT4520

#### Dual 4-bit synchronous binary counter

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